

PATENT NUMBER and

## U.S. UTILITY Patent Application

N-1	NUM 50171	FILING DATE 01/18/2002	GLASS	SUBCLASS 503	6847 <del>2812</del>	G	EXAMME	<u>P</u>		
**APF	**APPL!CANTS: Watanabe Kenichi; Waven									
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TITLE: Semiconductor device capable of suppressing current concentration in pad and its manufacture method  U.S.DEPT. OF COMM.PAT.& TM-PTO-435L(Rev. 12-94)										
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NOTICE OF ALLOWANCE MAILED	Assistant Examiner	CLAIMS ALLOWED  Total Claims  Print Claim for  0.0				
Amount Due Date Paid		Sheets Drug Figs Drug Print Fig.				
TERMINAL	Primary Examiner PREPARED F R ISSUE	Application Examiner				
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